

# PESD5V0X2UAM

# Ultra low capacitance unidirectional double ESD protection diode

10 April 2014

**Product data sheet** 

### 1. General description

Ultra low capacitance unidirectional double ElectroStatic Discharge (ESD) protection diode in a DFN1006-3 (SOT883) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect up to two signal lines from the damage caused by ESD and other transients.

#### 2. Features and benefits

- Ultra low diode capacitance: C<sub>d</sub> = 0.80 pF
- ESD protection up to 15 kV; IEC61000-4-2
- I<sub>PPM</sub> = 2.5 A; IEC 61643-321 (surge)
- AEC-Q101 qualified

### 3. Applications

- High-speed data lines
- Portable electronics
- Communication systems
- Computers and peripherals

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V	[1]	-	8.0	0.95	pF
V <sub>RWM</sub>	reverse standoff voltage			-	-	5	V

[1] Measured from pin 1 or 2 to 3.





# 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)	1 🔲	1
2	K2	cathode (diode 2)	2 3	2 3
3	А	common anode	Transparent top view	brb051
			DFN1006-3 (SOT883)	

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PESD5V0X2UAM	DFN1006-3	DFN1006-3: leadless ultra small plastic package; 3 solder lands	SOT883			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PESD5V0X2UAM	ZJ

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode						,
I <sub>PPM</sub>	rated peak pulse current	t <sub>p</sub> = 8/20 μs	[1][2]	-	2.5	Α
Tj	junction temperature			-	150	°C
T <sub>stg</sub>	storage temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
ESD maximu	um ratings		1			
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[3][2]	-	15	kV
		IEC 61000-4-2 (air discharge)	[3][2]	-	15	kV
		machine model	[2]	-	400	V
		MIL-STD-883 (human body model)		-	10	kV

- [1] According to IEC 61000-4-5 and IEC 61643-321.
- [2] Measured from pin 1 or 2 to 3.
- [3] Device stressed with ten non-repetitive ESD pulses.

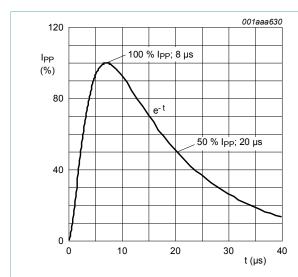


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

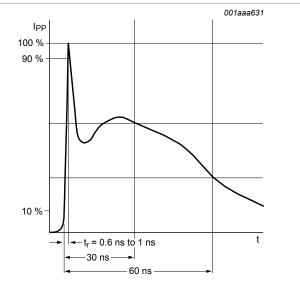


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

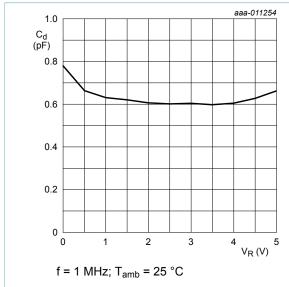
#### **Characteristics**

Table 6. **Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
$V_{RWM}$	reverse standoff voltage			-	-	5	V
I <sub>RM</sub>	reverse leakage current	V <sub>R</sub> = 5 V	[1]	-	1	10	nA
$V_{CL}$	clamping voltage	$I_{PP}$ = 1 A; $t_p$ = 8/20 $\mu$ s	[2][1]	-	-	13	V
		$I_{PP}$ = 2.5 A; $t_p$ = 8/20 µs	[2][1]	-	-	14	V
$V_{BR}$	breakdown voltage	I <sub>R</sub> = 10 mA	[1]	7.5	8.8	10	V
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V	[1]	-	0.8	0.95	pF
R <sub>dyn</sub>	dynamic resistance	I <sub>R</sub> = 10 A	[3][1]	-	0.65	-	Ω

- Measured from pin 1 or 2 to 3.
- According to IEC 61000-4-5 and IEC 61643-321.

  Non-repetitive current pulse, Transmission Line Pulse (TLP); square pulse; ANSI / ESD STM5.5.1-2008.



Diode capacitance as a function of reverse Fig. 3. voltage; typical values

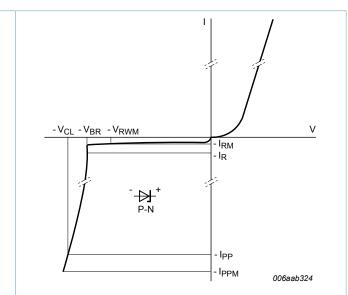
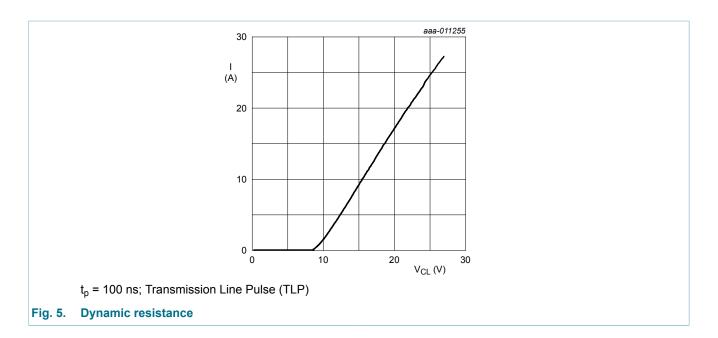
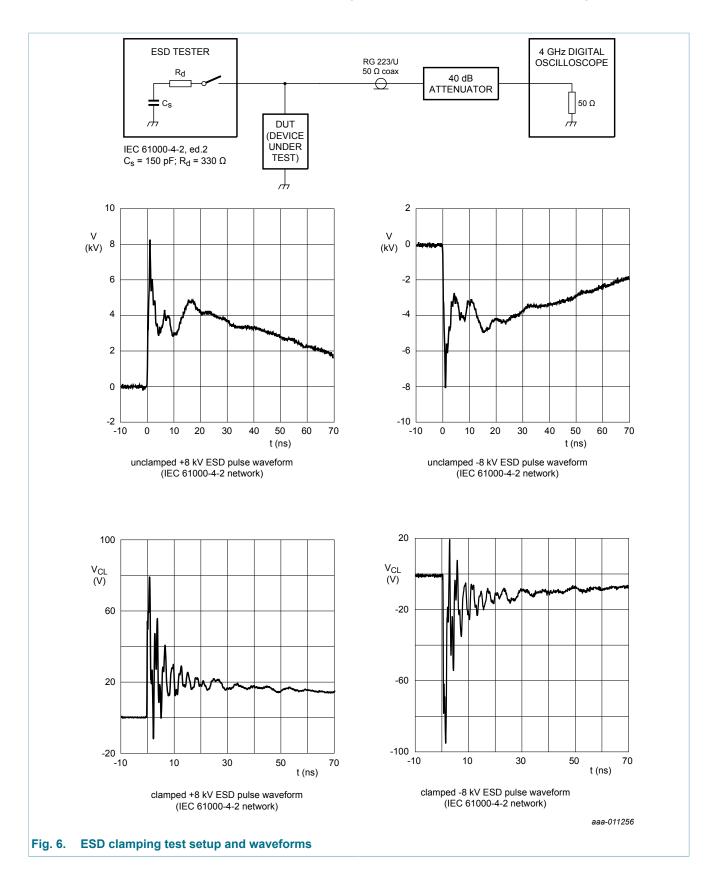


Fig. 4. V-I characteristics for a unidirectional ESD protection diode





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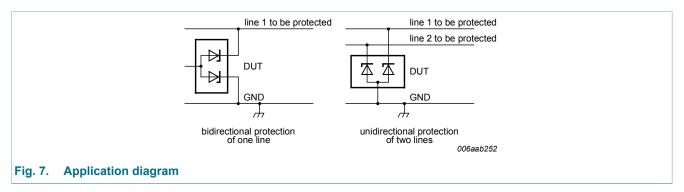
#### 10. Test information

#### 10.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 11. Application information

The device is designed for the protection of up to two unidirectional data lines from surge pulses and ESD damage.



#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

# 12. Package outline

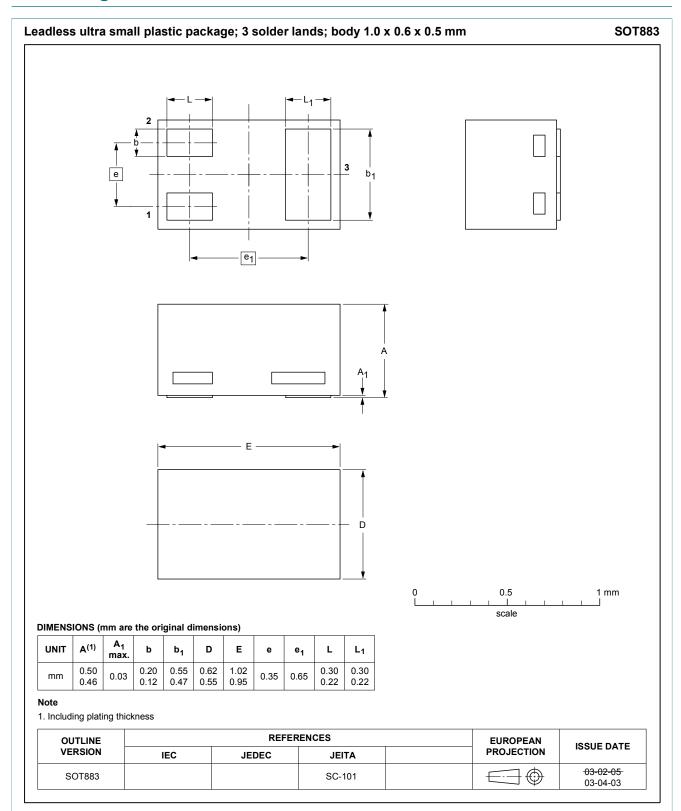
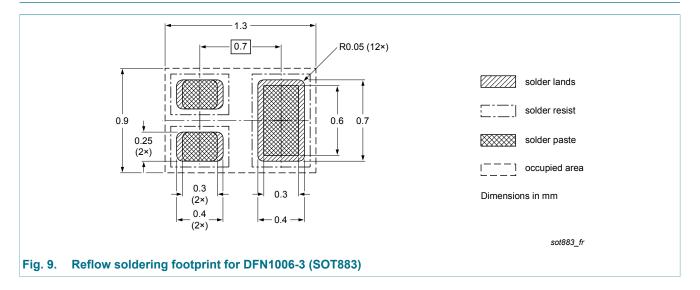


Fig. 8. Package outline DFN1006-3 (SOT883)

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# 13. Soldering



# 14. Revision history

#### Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0X2UAM v.1	20140410	Product data sheet	-	-

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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